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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	CIP-51 8051
Core Size	8-Bit
Speed	50MHz
Connectivity	I ² C, SMBus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	22
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2.25K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 20x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	28-WFQFN Exposed Pad
Supplier Device Package	28-QFN (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm8bb22f16g-b-qfn28r

Ordering Part Number	Flash Memory (KB)	RAM (Bytes)	Digital Port I/Os (Total)	ADC0 Channels	Comparator 0 Inputs	Comparator 1 Inputs	Pb-free (RoHS Compliant)	5-to-3.3 V Regulator	Temperature Range	Package
EFM8BB21F16I-C-QFN20	16	2304	16	15	10	7	Yes	_	-40 to +125 °C	QFN20
EFM8BB22F16A-C-QFN28	16	2304	22	20	10	12	Yes	Yes	-40 to +125 °C	QFN28
EFM8BB21F16A-C-QFN20	16	2304	16	15	10	7	Yes	_	-40 to +125 °C	QFN20

The A-grade (i.e. EFM8BB21F16A-C-QFN20) devices receive full automotive quality production status, including AEC-Q100 qualification, registration with International Material Data System (IMDS), and Part Production Approval Process (PPAP) documentation. PPAP documentation is available at www.silabs.com with a registered and NDA approved user account.

3.2 Power

All internal circuitry draws power from the VDD supply pin. External I/O pins are powered from the VIO supply voltage (or VDD on devices without a separate VIO connection), while most of the internal circuitry is supplied by an on-chip LDO regulator. Control over the device power can be achieved by enabling/disabling individual peripherals as needed. Each analog peripheral can be disabled when not in use and placed in low power mode. Digital peripherals, such as timers and serial buses, have their clocks gated off and draw little power when they are not in use.

Table 3.1. Power Modes

Power Mode	Details	Mode Entry	Wake-Up Sources
Normal	Core and all peripherals clocked and fully operational	_	_
Idle	 Core halted All peripherals clocked and fully operational Code resumes execution on wake event 	Set IDLE bit in PCON0	Any interrupt
Suspend	 Core and peripheral clocks halted HFOSC0 and HFOSC1 oscillators stopped Regulators in normal bias mode for fast wake Timer 3 and 4 may clock from LFOSC0 Code resumes execution on wake event 	1. Switch SYSCLK to HFOSC0 2. Set SUSPEND bit in PCON1	 Timer 4 Event SPI0 Activity I2C0 Slave Activity Port Match Event Comparator 0 Falling Edge
Stop	 All internal power nets shut down 5 V regulator remains active (if enabled) Internal 1.8 V LDO on Pins retain state Exit on any reset source 	1. Clear STOPCF bit in REG0CN 2. Set STOP bit in PCON0	Any reset source
Snooze	 Core and peripheral clocks halted HFOSC0 and HFOSC1 oscillators stopped Regulators in low bias current mode for energy savings Timer 3 and 4 may clock from LFOSC0 Code resumes execution on wake event 	1. Switch SYSCLK to HFOSC0 2. Set SNOOZE bit in PCON1	 Timer 4 Event SPI0 Activity I2C0 Slave Activity Port Match Event Comparator 0 Falling Edge
Shutdown	 All internal power nets shut down 5 V regulator remains active (if enabled) Internal 1.8 V LDO off to save energy Pins retain state Exit on pin or power-on reset 	1. Set STOPCF bit in REG0CN 2. Set STOP bit in PCON0	RSTb pin reset Power-on reset

3.3 I/O

Digital and analog resources are externally available on the device's multi-purpose I/O pins. Port pins P0.0-P2.3 can be defined as general-purpose I/O (GPIO), assigned to one of the internal digital resources through the crossbar or dedicated channels, or assigned to an analog function. Port pins P3.0 and P3.1 can be used as GPIO. Additionally, the C2 Interface Data signal (C2D) is shared with P3.0.

The port control block offers the following features:

- Up to 22 multi-functions I/O pins, supporting digital and analog functions.
- · Flexible priority crossbar decoder for digital peripheral assignment.
- · Two drive strength settings for each port.
- · Two direct-pin interrupt sources with dedicated interrupt vectors (INT0 and INT1).
- · Up to 20 direct-pin interrupt sources with shared interrupt vector (Port Match).

Universal Asynchronous Receiver/Transmitter (UART1)

UART1 is an asynchronous, full duplex serial port offering a variety of data formatting options. A dedicated baud rate generator with a 16-bit timer and selectable prescaler is included, which can generate a wide range of baud rates. A received data FIFO allows UART1 to receive multiple bytes before data is lost and an overflow occurs.

UART1 provides the following features:

- · Asynchronous transmissions and receptions.
- Dedicated baud rate generator supports baud rates up to SYSCLK/2 (transmit) or SYSCLK/8 (receive).
- 5, 6, 7, 8, or 9 bit data.
- · Automatic start and stop generation.
- · Automatic parity generation and checking.
- · Four byte FIFO on transmit and receive.
- · Auto-baud detection.
- · LIN break and sync field detection.
- · CTS / RTS hardware flow control.

Serial Peripheral Interface (SPI0)

The serial peripheral interface (SPI) module provides access to a flexible, full-duplex synchronous serial bus. The SPI can operate as a master or slave device in both 3-wire or 4-wire modes, and supports multiple masters and slaves on a single SPI bus. The slave-select (NSS) signal can be configured as an input to select the SPI in slave mode, or to disable master mode operation in a multi-master environment, avoiding contention on the SPI bus when more than one master attempts simultaneous data transfers. NSS can also be configured as a firmware-controlled chip-select output in master mode, or disabled to reduce the number of pins required. Additional general purpose port I/O pins can be used to select multiple slave devices in master mode.

- · Supports 3- or 4-wire master or slave modes.
- · Supports external clock frequencies up to 12 Mbps in master or slave mode.
- · Support for all clock phase and polarity modes.
- · 8-bit programmable clock rate (master).
- · Programmable receive timeout (slave).
- · Four byte FIFO on transmit and receive.
- Can operate in suspend or snooze modes and wake the CPU on reception of a byte.
- Support for multiple masters on the same data lines.

System Management Bus / I2C (SMB0)

The SMBus I/O interface is a two-wire, bi-directional serial bus. The SMBus is compliant with the System Management Bus Specification, version 1.1, and compatible with the I²C serial bus.

The SMBus module includes the following features:

- Standard (up to 100 kbps) and Fast (400 kbps) transfer speeds
- · Support for master, slave, and multi-master modes
- · Hardware synchronization and arbitration for multi-master mode
- · Clock low extending (clock stretching) to interface with faster masters
- Hardware support for 7-bit slave and general call address recognition
- · Firmware support for 10-bit slave address decoding
- · Ability to inhibit all slave states
- · Programmable data setup/hold times
- Transmit and receive FIFOs (one byte) to help increase throughput in faster applications

I2C Slave (I2CSLAVE0)

The I2C Slave interface is a 2-wire, bidirectional serial bus that is compatible with the I2C Bus Specification 3.0. It is capable of transferring in high-speed mode (HS-mode) at speeds of up to 3.4 Mbps. Firmware can write to the I2C interface, and the I2C interface can autonomously control the serial transfer of data. The interface also supports clock stretching for cases where the core may be temporarily prohibited from transmitting a byte or processing a received byte during an I2C transaction. This module operates only as an I2C slave device.

The I2C module includes the following features:

- Standard (up to 100 kbps), Fast (400 kbps), Fast Plus (1 Mbps), and High-speed (3.4 Mbps) transfer speeds
- · Support for slave mode only
- · Clock low extending (clock stretching) to interface with faster masters
- · Hardware support for 7-bit slave address recognition
- Transmit and receive FIFOs (two bytes) to help increase throughput in faster applications

16-bit CRC (CRC0)

The cyclic redundancy check (CRC) module performs a CRC using a 16-bit polynomial. CRC0 accepts a stream of 8-bit data and posts the 16-bit result to an internal register. In addition to using the CRC block for data manipulation, hardware can automatically CRC the flash contents of the device.

The CRC module is designed to provide hardware calculations for flash memory verification and communications protocols. The CRC module supports the standard CCITT-16 16-bit polynomial (0x1021), and includes the following features:

- · Support for CCITT-16 polynomial
- · Byte-level bit reversal
- · Automatic CRC of flash contents on one or more 256-byte blocks
- Initial seed selection of 0x0000 or 0xFFFF

3.7 Analog

12-Bit Analog-to-Digital Converter (ADC0)

The ADC is a successive-approximation-register (SAR) ADC with 12-, 10-, and 8-bit modes, integrated track-and hold and a programmable window detector. The ADC is fully configurable under software control via several registers. The ADC may be configured to measure different signals using the analog multiplexer. The voltage reference for the ADC is selectable between internal and external reference sources.

- Up to 20 external inputs.
- · Single-ended 12-bit and 10-bit modes.
- Supports an output update rate of 200 ksps samples per second in 12-bit mode or 800 ksps samples per second in 10-bit mode.
- · Operation in low power modes at lower conversion speeds.
- Asynchronous hardware conversion trigger, selectable between software, external I/O and internal timer sources.
- Output data window comparator allows automatic range checking.
- Support for burst mode, which produces one set of accumulated data per conversion-start trigger with programmable power-on settling and tracking time.
- · Conversion complete and window compare interrupts supported.
- Flexible output data formatting.
- · Includes an internal fast-settling reference with two levels (1.65 V and 2.4 V) and support for external reference and signal ground.
- · Integrated temperature sensor.

Low Current Comparators (CMP0, CMP1)

Analog comparators are used to compare the voltage of two analog inputs, with a digital output indicating which input voltage is higher. External input connections to device I/O pins and internal connections are available through separate multiplexers on the positive and negative inputs. Hysteresis, response time, and current consumption may be programmed to suit the specific needs of the application.

The comparator includes the following features:

- Up to 10 (CMP0) or 12 (CMP1) external positive inputs
- Up to 10 (CMP0) or 12 (CMP1) external negative inputs
- · Additional input options:
 - · Internal connection to LDO output
 - · Direct connection to GND
 - · Direct connection to VDD
 - · Dedicated 6-bit reference DAC
- · Synchronous and asynchronous outputs can be routed to pins via crossbar
- Programmable hysteresis between 0 and ±20 mV
- Programmable response time
- · Interrupts generated on rising, falling, or both edges
- · PWM output kill feature

3.8 Reset Sources

Reset circuitry allows the controller to be easily placed in a predefined default condition. On entry to this reset state, the following occur:

- The core halts program execution.
- · Module registers are initialized to their defined reset values unless the bits reset only with a power-on reset.
- External port pins are forced to a known state.
- · Interrupts and timers are disabled.

All registers are reset to the predefined values noted in the register descriptions unless the bits only reset with a power-on reset. The contents of RAM are unaffected during a reset; any previously stored data is preserved as long as power is not lost. The Port I/O latches are reset to 1 in open-drain mode. Weak pullups are enabled during and after the reset. For Supply Monitor and power-on resets, the RSTb pin is driven low until the device exits the reset state. On exit from the reset state, the program counter (PC) is reset, and the system clock defaults to an internal oscillator. The Watchdog Timer is enabled, and program execution begins at location 0x0000.

Reset sources on the device include the following:

- Power-on reset
- · External reset pin
- Comparator reset
- · Software-triggered reset
- Supply monitor reset (monitors VDD supply)
- Watchdog timer reset
- · Missing clock detector reset
- · Flash error reset

3.9 Debugging

The EFM8BB2 devices include an on-chip Silicon Labs 2-Wire (C2) debug interface to allow flash programming and in-system debugging with the production part installed in the end application. The C2 interface uses a clock signal (C2CK) and a bi-directional C2 data signal (C2D) to transfer information between the device and a host system. See the C2 Interface Specification for details on the C2 protocol.

3.10 Bootloader

All devices come pre-programmed with a UART bootloader. This bootloader resides in the code security page and last page of code flash; it can be erased if it is not needed.

The byte before the Lock Byte is the Bootloader Signature Byte. Setting this byte to a value of 0xA5 indicates the presence of the bootloader in the system. Any other value in this location indicates that the bootloader is not present in flash.

When a bootloader is present, the device will jump to the bootloader vector after any reset, allowing the bootloader to run. The bootloader then determines if the device should stay in bootload mode or jump to the reset vector located at 0x0000. When the bootloader is not present, the device will jump to the reset vector of 0x0000 after any reset.

More information about the bootloader protocol and usage can be found in *AN945: EFM8 Factory Bootloader User Guide*. Application notes can be found on the Silicon Labs website (www.silabs.com/8bit-appnotes) or within Simplicity Studio by using the [**Application Notes**] tile.

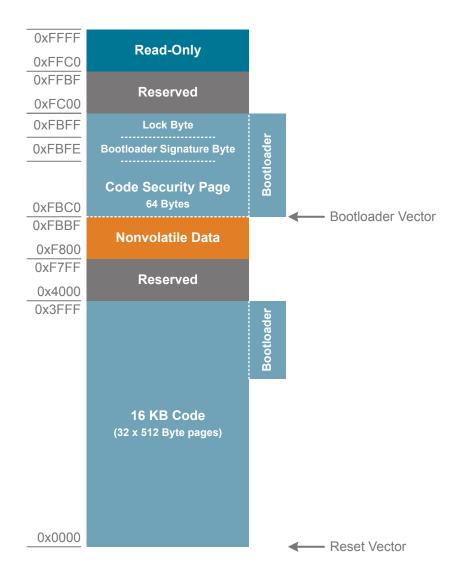


Figure 3.2. Flash Memory Map with Bootloader—16 KB Devices

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Stop Mode—Core halted and all clocks stopped,Internal LDO On, Supply monitor off.	I _{DD}		_	120	1045	μА
Shutdown Mode—Core halted and all clocks stopped,Internal LDO Off, Supply monitor off.	I _{DD}		_	0.2	15	μА
Analog Peripheral Supply Curren	ts (-40 °C to	+125 °C)				
High-Frequency Oscillator 0	I _{HFOSC0}	Operating at 24.5 MHz, $T_A = 25 ^{\circ}\text{C}$	_	105	_	μΑ
High-Frequency Oscillator 1	I _{HFOSC1}	Operating at 49 MHz,	_	865	940	μА
		T _A = 25 °C				
Low-Frequency Oscillator	I _{LFOSC}	Operating at 80 kHz,	_	4	_	μA
		T _A = 25 °C				
ADC0 Always-on ⁴	I _{ADC}	800 ksps, 10-bit conversions or	_	820	1200	μΑ
		200 ksps, 12-bit conversions				
		Normal bias settings				
		V _{DD} = 3.0 V				
		250 ksps, 10-bit conversions or	_	405	580	μA
		62.5 ksps 12-bit conversions				
		Low power bias settings				
		V _{DD} = 3.0 V				
ADC0 Burst Mode, 10-bit single conversions, external reference	I _{ADC}	200 ksps, V _{DD} = 3.0 V	_	370	_	μΑ
Conversions, external reference		100 ksps, V _{DD} = 3.0 V	_	185	_	μA
		10 ksps, V _{DD} = 3.0 V	_	20	_	μA
ADC0 Burst Mode, 10-bit single	I _{ADC}	200 ksps, V _{DD} = 3.0 V	_	485	_	μА
conversions, internal reference, Low power bias settings		100 ksps, V _{DD} = 3.0 V	_	245	_	μА
		10 ksps, V _{DD} = 3.0 V	_	25	_	μА
ADC0 Burst Mode, 12-bit single	I _{ADC}	100 ksps, V _{DD} = 3.0 V	_	505	_	μΑ
conversions, external reference		50 ksps, V _{DD} = 3.0 V	_	255	_	μΑ
		10 ksps, V _{DD} = 3.0 V	_	50	_	μΑ
ADC0 Burst Mode, 12-bit single	I _{ADC}	100 ksps, V _{DD} = 3.0 V,	_	950	_	μА
conversions, internal reference		Normal bias				
		50 ksps, V _{DD} = 3.0 V,	_	415	_	μΑ
		Low power bias				
		10 ksps, V _{DD} = 3.0 V,	_	80	_	μΑ
		Low power bias				
Internal ADC0 Reference, Always-	I _{VREFFS}	Normal Power Mode	_	680	790	μΑ
on ⁵		Low Power Mode	_	160	210	μΑ

4.1.7 External Clock Input

Table 4.7. External Clock Input

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
External Input CMOS Clock	f _{CMOS}		0	_	50	MHz
Frequency (at EXTCLK pin)						
External Input CMOS Clock High Time	t _{CMOSH}		9	_	_	ns
External Input CMOS Clock Low Time	tcmosL		9	_	_	ns

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Slope Error	E _M	12 Bit Mode	_	±0.02	±0.1	%
		10 Bit Mode	_	±0.06	±0.24	%
Dynamic Performance 10 kHz Si	ne Wave Inp	out 1 dB below full scale, Max throug	ghput, using	AGND pin		
Signal-to-Noise	SNR	12 Bit Mode	61	66	_	dB
		10 Bit Mode	53	60	_	dB
Signal-to-Noise Plus Distortion	SNDR	12 Bit Mode	61	66	_	dB
		10 Bit Mode	53	60	_	dB
Total Harmonic Distortion (Up to	THD	12 Bit Mode	_	71	_	dB
5th Harmonic)		10 Bit Mode	_	70	_	dB
Spurious-Free Dynamic Range	SFDR	12 Bit Mode	_	-79	_	dB
		10 Bit Mode	_	-70	_	dB

Note:

4.1.9 Voltage Reference

Table 4.9. Voltage Reference

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Internal Fast Settling Reference						
Output Voltage	V _{REFFS}	1.65 V Setting	1.62	1.65	1.68	V
(Full Temperature and Supply Range)		2.4 V Setting, V _{DD} > 2.6 V	2.35	2.4	2.45	V
Temperature Coefficient	TC _{REFFS}		_	50	_	ppm/°C
Turn-on Time	t _{REFFS}		_	_	1.5	μs
Power Supply Rejection	PSRR _{REF} FS		_	400	_	ppm/V
External Reference			1	1		1
Input Current	I _{EXTREF}	Sample Rate = 800 ksps; VREF = 3.0 V	_	8	_	μА

^{1.} Absolute input pin voltage is limited by the $\ensuremath{V_{DD}}$ supply.

4.1.10 Temperature Sensor

Table 4.10. Temperature Sensor

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Offset	V _{OFF}	T _A = 0 °C	_	757	_	mV
Offset Error ¹	E _{OFF}	T _A = 0 °C	_	17	_	mV
Slope	M		_	2.85	_	mV/°C
Slope Error ¹	E _M		_	70	_	μV/°
Linearity			_	0.5	_	°C
Turn-on Time			_	1.8	_	μs

Note:

4.1.11 1.8 V Internal LDO Voltage Regulator

Table 4.11. 1.8V Internal LDO Voltage Regulator

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Output Voltage	V _{OUT_1.8V}		1.78	1.85	1.92	V

4.1.12 5 V Voltage Regulator

Table 4.12. 5V Voltage Regulator

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Input Voltage Range ¹	V _{REGIN}		3.0	_	5.25	V
Output Voltage on VDD ²	V _{REGOUT}	REGOUT Output Current = 1 to 100 mA		3.3	3.6	V
		Regulation range (VREGIN ≥ 4.1 V)				
		Output Current = 1 to 100 mA	_	V _{REGIN} –	_	V
		Dropout range (VREGIN < 4.1 V)		V _{DROPOUT}		
Output Current ²	I _{REGOUT}		_	_	100	mA
Dropout Voltage	V _{DROPOUT}	Output Current = 100 mA	_	_	0.8	V

Note:

- 1. Input range to meet the Output Voltage on VDD specification. If the 5V voltage regulator is not used, VREGIN should be tied to VDD.
- 2. Output current is total regulator output, including any current required by the device.

^{1.} Represents one standard deviation from the mean.

4.4 Typical Performance Curves

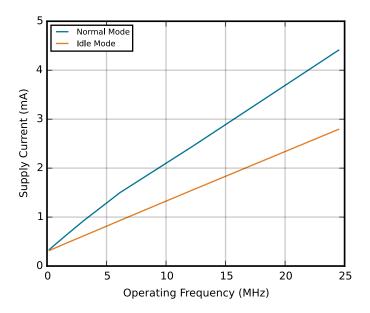


Figure 4.1. Typical Operating Supply Current using HFOSC0

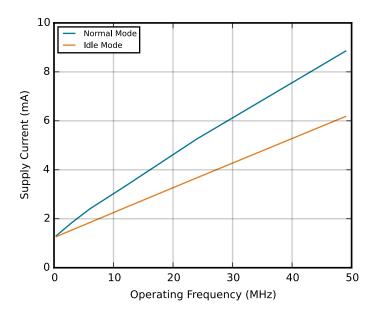


Figure 4.2. Typical Operating Supply Current using HFOSC1

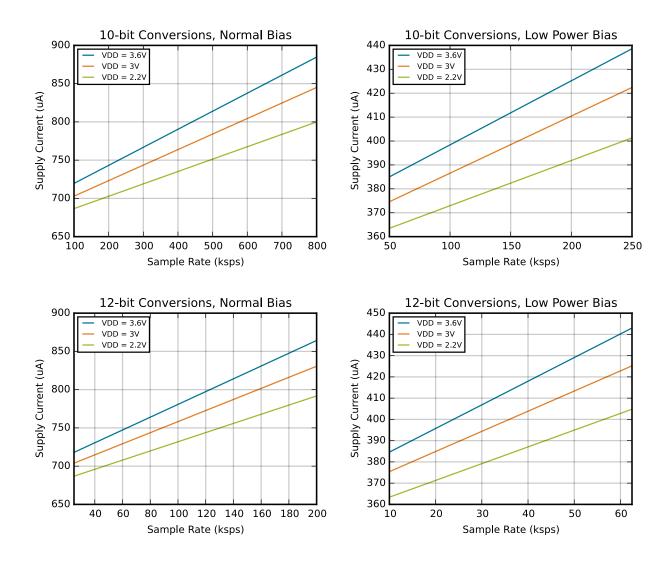


Figure 4.5. Typical ADC0 Supply Current in Normal (always-on) Mode

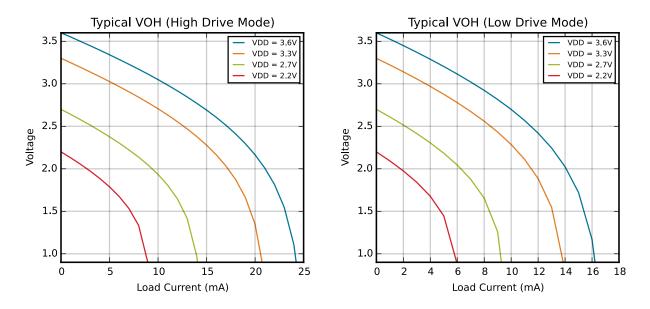


Figure 4.6. Typical V_{OH} Curves

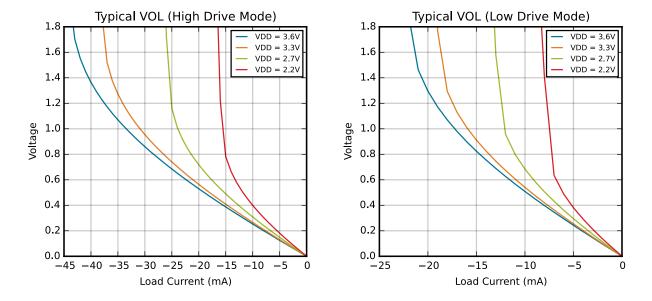


Figure 4.7. Typical V_{OL} Curves

5. Typical Connection Diagrams

5.1 Power

Figure 5.1 Connection Diagram with Voltage Regulator Used on page 29 shows a typical connection diagram for the power pins of the EFM8BB2 devices when the 5 V-to-3.3 V regulator is in use.

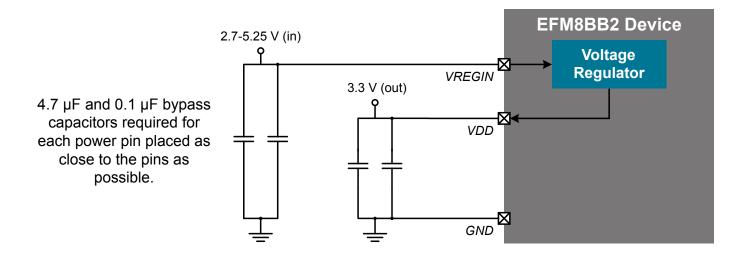


Figure 5.1. Connection Diagram with Voltage Regulator Used

Figure 5.2 Connection Diagram with Voltage Regulator Not Used on page 29 shows a typical connection diagram for the power pins of the EFM8BB2 devices when the internal 5 V-to-3.3 V regulator is not used.

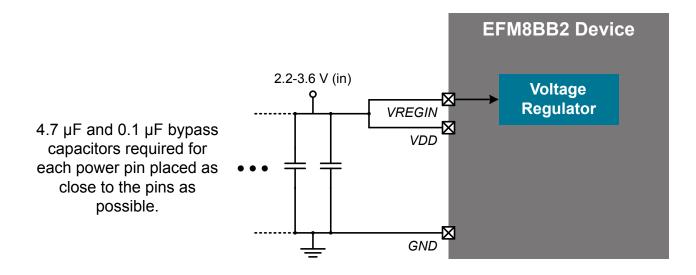


Figure 5.2. Connection Diagram with Voltage Regulator Not Used

5.2 Debug

The diagram below shows a typical connection diagram for the debug connections pins. The pin sharing resistors are only required if the functionality on the C2D (a GPIO pin) and the C2CK (RSTb) is routed to external circuitry. For example, if the RSTb pin is connected to an external switch with debouncing filter or if the GPIO sharing with the C2D pin is connected to an external circuit, the pin sharing resistors and connections to the debug adapter must be placed on the hardware. Otherwise, these components and connections can be omitted.

For more information on debug connections, see the example schematics and information available in AN127: "Pin Sharing Techniques for the C2 Interface." Application notes can be found on the Silicon Labs website (http://www.silabs.com/8bit-appnotes) or in Simplicity Studio.

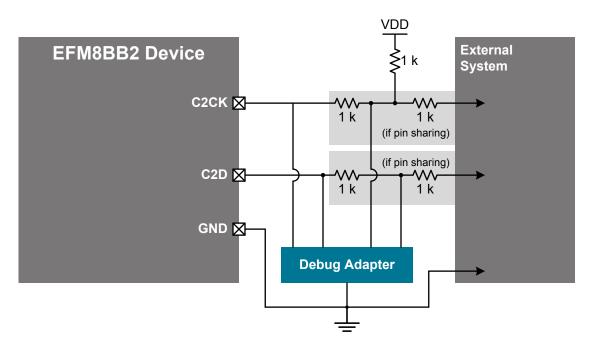


Figure 5.3. Debug Connection Diagram

5.3 Other Connections

Other components or connections may be required to meet the system-level requirements. Application note, "AN203: 8-bit MCU Printed Circuit Board Design Notes", contains detailed information on these connections. Application Notes can be accessed on the Silicon Labs website (www.silabs.com/8bit-appnotes).

6.2 EFM8BB2x-QSOP24 Pin Definitions

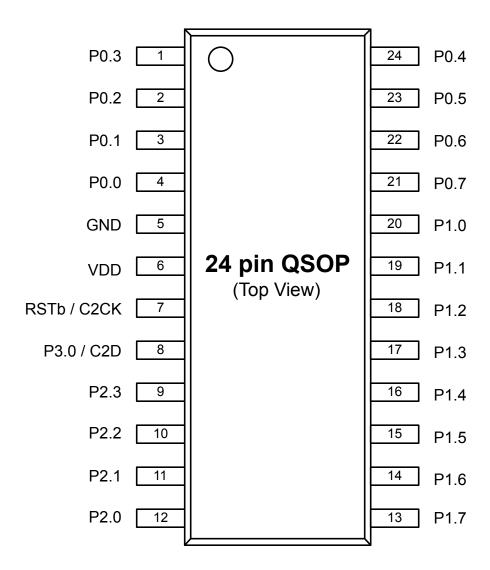


Figure 6.2. EFM8BB2x-QSOP24 Pinout

Table 6.2. Pin Definitions for EFM8BB2x-QSOP24

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
1	P0.3	Multifunction I/O	Yes	P0MAT.3	ADC0.3
				EXTCLK	CMP0P.3
				INT0.3	CMP0N.3
				INT1.3	
2	P0.2	Multifunction I/O	Yes	P0MAT.2	ADC0.2
				INT0.2	CMP0P.2
				INT1.2	CMP0N.2

8.2 QSOP24 PCB Land Pattern

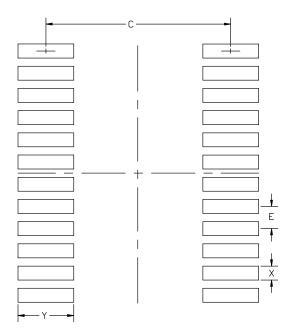


Figure 8.2. QSOP24 PCB Land Pattern Drawing

Table 8.2. QSOP24 PCB Land Pattern Dimensions

Dimension	Min	Мах			
С	5.20	5.30			
E	0.635 BSC				
Х	0.30	0.40			
Υ	1.50	1.60			

Note:

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. This land pattern design is based on the IPC-7351 guidelines.
- 3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μ m minimum, all the way around the pad.
- 4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 5. The stencil thickness should be 0.125 mm (5 mils).
- 6. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
- 7. A No-Clean, Type-3 solder paste is recommended.
- 8. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

9. QFN20 Package Specifications

9.1 QFN20 Package Dimensions

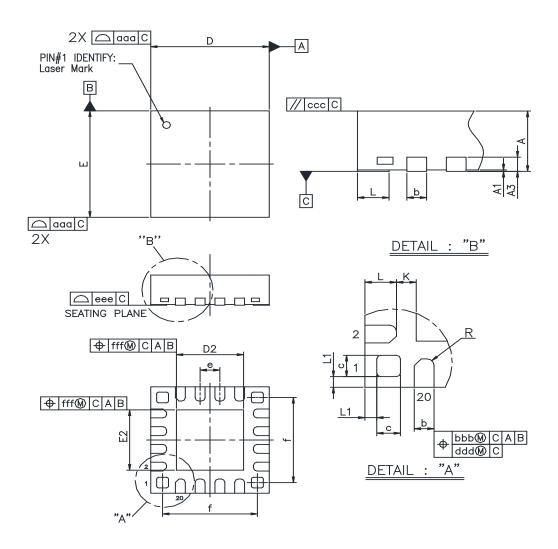


Figure 9.1. QFN20 Package Drawing

Table 9.1. QFN20 Package Dimensions

Dimension	Min	Тур	Max
А	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3	0.20 REF		
b	0.18	0.25	0.30
С	0.25	0.30	0.35
D	3.00 BSC		
D2	1.6	1.70	1.80
е	0.50 BSC		

1.60	3.00 BSC			
1 60		3.00 BSC		
1.00	1.70	1.80		
2.50 BSC				
0.30	0.40	0.50		
0.25 REF				
0.09	0.125	0.15		
0.15				
0.10				
0.10				
0.05				
0.08				
0.10				
		0.30 0.40 0.25 REF 0.09 0.125 0.15 0.10 0.10 0.05 0.08		

Note:

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. The drawing complies with JEDEC MO-220.
- 4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

9.2 QFN20 PCB Land Pattern

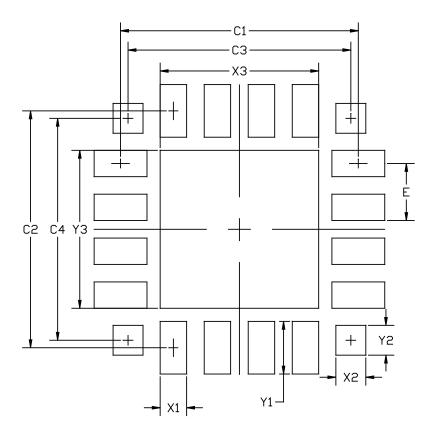


Figure 9.2. QFN20 PCB Land Pattern Drawing

Table 9.2. QFN20 PCB Land Pattern Dimensions

Dimension	Min	Max	
C1	3.10		
C2	3.10		
C3	2.50		
C4	2.50		
E	0.50		
X1	0.30		
X2	0.25	0.35	
X3	1.80		
Y1	0.90		
Y2	0.25	0.35	
Y3	1.80		